國立成功大學 110學年度碩士班招生考試試題

編 號: 121

系 所:工程科學系

科 目:電子電路

日 期: 0203

節 次:第1節

備 註:可使用計算機

國立成功大學 110 學年度碩士班招生考試試題

系 所:工程科學系 考試科目:電子電路

考試日期:0203,節次:1

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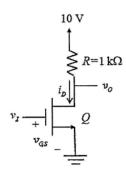
編號: 121

- ※ 考生請注意:本試題可使用計算機。 請於答案卷(卡)作答,於本試題紙上作答者,不予計分。
- 1. Mark each of the following statements True (T) or False (F). (Need NOT give reasons.) (20 pt.)
 - (a) The current mirror must operate in the saturation region because it is used to amplify the signal source.
 - (b) The large signal means the DC voltage.
 - (c) We often cannot ignore the output resistance r_o of a transistor when analyzing an IC amp so that the voltages in intermediate nodes of an IC amp can be determined.
 - (d) When performing AC (midband) analysis, the capacitors including coupling, bypass, and internal parasitic capacitors should be opened circuit because their impedances are zero.
 - (e) Small-signal assumption makes the characteristics of transistors become linear.
 - (f) Transistors of MOSFET and BJT are basically nonlinear devices.
 - (g) The breakdown of typical diodes (except Zener diodes) is not considered because we must guarantee that the region is never entered.
 - (h) Voltage buffers typically provide large gain, high input resistance, and low output resistance.
 - (i) Analog signals are more convenient to process than digital signals.
 - (i) The characteristics of amplifiers depend strongly on the DC operating point.
- 2. A new N-type transistor, Q, using the same symbol of the conventional NMOS, is the same as the conventional NMOS in all aspects except the following $i_D v_{GS}$ characteristics in the saturation region:

$$i_D = k \left(v_{GS} - V_t \right)^3$$

where k=5 mA/V³ is a constant, and $V_t=1$ V denotes the threshold voltage. Find the small-signal

voltage gain
$$A_{\nu} \equiv \frac{v_o}{v_i}$$
 when $V_I = V_{GS} = 2$ V. (20 pt.)



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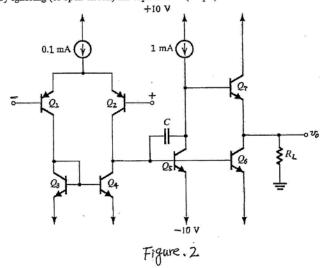
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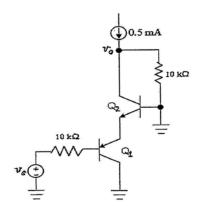
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3. Figure 2 shows a circuit suitable for op-amp application. For all transistors $\beta = 100$, $V_{BE} = 0.7$ V, $|V_T| = 25$ mV, and $r_o = \infty$. For dc analysis, you can ignore base currents and input dc voltages are zero. Calculate the gain of the amp with a load of $10 \text{ k}\Omega$ by ignoring (or open-circuit) the capacitor C. (20 pt.)



4. The transistors are biased by a current source such that the transistors have $\beta = 100$, $r_{\pi} = 5 \text{ k}\Omega$, $g_{\pi} = 20 \text{ mA/V}$, $r_{o} = \infty$. Find the gain of the amp. (20 pt.)



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5. A commercial μ A741 is employed in the noninverting configuration, $R_1 = 1 k\Omega$ and $R_2 = 9 k\Omega$. The op amp has

its open-loop gain (or transfer function) as $A(s) = \frac{10^4}{1 + \frac{s}{2\pi \times 100}}$. If the input signal is $0.1\sin(2\pi \times 100 \times 10^3 t)$,

that is, frequency=100 kHz and amplitude=0.1 V, obtain the output signal. (Note that $1/\sqrt{2} = 0.707$) (20 pt.)

